



Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at
www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.



September 2015

MOC3061M, MOC3062M, MOC3063M, MOC3162M, MOC3163M 6-Pin DIP Zero-Cross Triac Driver Optocoupler (600 Volt Peak)

Features

- Simplifies Logic Control of 115/240 VAC Power
- Zero Voltage Crossing to Minimize Conducted and Radiated Line Noise
- 600 V Peak Blocking Voltage
- Superior Static dv/dt
 - 600 V/ μ s (MOC306xM)
 - 1000 V/ μ s (MOC316xM)
- Safety and Regulatory Approvals
 - UL1577, 4,170 VAC_{RMS} for 1 Minute
 - DIN EN/IEC60747-5-5

Applications

- Solenoid/Valve Controls
- Static Power Switches
- Temperature Controls
- AC Motor Starters
- Lighting Controls
- AC Motor Drives
- E.M. Contactors
- Solid State Relays

Description

The MOC306XM and MOC316XM devices consist of a GaAs infrared emitting diode optically coupled to a monolithic silicon detector performing the function of a zero voltage crossing bilateral triac driver.

They are designed for use with a triac in the interface of logic systems to equipment powered from 115/240 VAC lines, such as solid-state relays, industrial controls, motors, solenoids and consumer appliances, etc.

Schematic

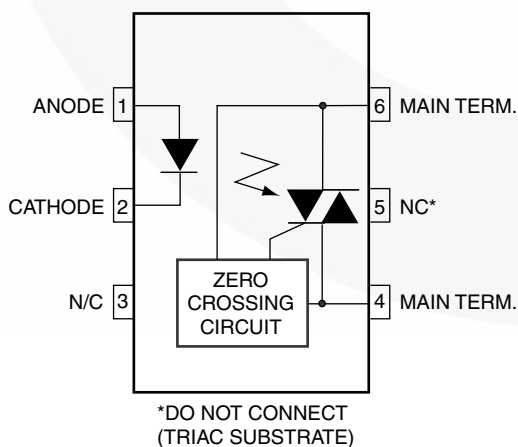


Figure 1. Schematic

Package Outlines



Figure 2. Package Outlines

MOC306XM, MOC316XM — 6-Pin DIP Zero-Cross Triac Driver Optocoupler (600 Volt Peak)

Safety and Insulation Ratings

As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for “safe electrical insulation” only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

| Parameter | | Characteristics |
|---|------------------------|-----------------|
| Installation Classifications per DIN VDE 0110/1.89 Table 1, For Rated Mains Voltage | < 150 V _{RMS} | I–IV |
| | < 300 V _{RMS} | I–IV |
| Climatic Classification | | 40/85/21 |
| Pollution Degree (DIN VDE 0110/1.89) | | 2 |
| Comparative Tracking Index | | 175 |

| Symbol | Parameter | Value | Unit |
|-------------------|--|-------------------|-------------------|
| V _{PR} | Input-to-Output Test Voltage, Method A, V _{IORM} × 1.6 = V _{PR} , Type and Sample Test with t _m = 10 s, Partial Discharge < 5 pC | 1360 | V _{peak} |
| | Input-to-Output Test Voltage, Method B, V _{IORM} × 1.875 = V _{PR} , 100% Production Test with t _m = 1 s, Partial Discharge < 5 pC | 1594 | V _{peak} |
| V _{IORM} | Maximum Working Insulation Voltage | 850 | V _{peak} |
| V _{IOTM} | Highest Allowable Over-Voltage | 6000 | V _{peak} |
| | External Creepage | ≥ 7 | mm |
| | External Clearance | ≥ 7 | mm |
| | External Clearance (for Option TV, 0.4" Lead Spacing) | ≥ 10 | mm |
| DTI | Distance Through Insulation (Insulation Thickness) | ≥ 0.5 | mm |
| R _{IO} | Insulation Resistance at T _S , V _{IO} = 500 V | > 10 ⁹ | Ω |

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $T_A = 25^\circ\text{C}$ unless otherwise specified.

| Symbol | Parameters | Device | Value | Unit |
|---------------------|---|--------|-----------------------|----------------------|
| TOTAL DEVICE | | | | |
| T_{STG} | Storage Temperature | All | -40 to +150 | $^\circ\text{C}$ |
| T_{OPR} | Operating Temperature | All | -40 to +85 | $^\circ\text{C}$ |
| T_J | Junction Temperature Range | All | -40 to +100 | $^\circ\text{C}$ |
| T_{SOL} | Lead Solder Temperature | All | 260 for 10 seconds | $^\circ\text{C}$ |
| P_D | Total Device Power Dissipation at 25°C Ambient | All | 250 | mW |
| | Derate Above 25°C | | 2.94 | mW/ $^\circ\text{C}$ |
| EMITTER | | | | |
| I_F | Continuous Forward Current | All | 60 | mA |
| V_R | Reverse Voltage | All | 6 | V |
| P_D | Total Power Dissipation at 25°C Ambient | All | 120 | mW |
| | Derate Above 25°C | | 1.41 | mW/ $^\circ\text{C}$ |
| DETECTOR | | | | |
| V_{DRM} | Off-State Output Terminal Voltage | All | 600 | V |
| I_{TSM} | Peak Non-Repetitive Surge Current (Single Cycle 60 Hz Sine Wave) | All | 1 | A |
| P_D | Total Power Dissipation at 25°C Ambient | All | 150 | mW |
| | Derate Above 25°C | | 1.76 | mW/ $^\circ\text{C}$ |

Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise specified.

Individual Component Characteristics

| Symbol | Parameters | Test Conditions | Device | Min. | Typ. | Max. | Unit |
|-------------------|--|---|----------------------|-------------|----------|------------|------------------|
| EMITTER | | | | | | | |
| V_F | Input Forward Voltage | $I_F = 30\text{ mA}$ | All | | 1.3 | 1.5 | V |
| I_R | Reverse Leakage Current | $V_R = 6\text{ V}$ | All | | 0.005 | 100 | μA |
| DETECTOR | | | | | | | |
| I_{DRM1} | Peak Blocking Current, Either Direction | $V_{\text{DRM}} = 600\text{ V}$, $I_F = 0^{(1)}$ | MOC306XM MOC316XM | | 10 10 | 500 100 | nA |
| dv/dt | Critical Rate of Rise of Off-State Voltage | $I_F = 0$ (Figure 11) ⁽²⁾ | MOC306XM MOC316XM | 600 1000 | 1500 | | V/ μs |

Transfer Characteristics

| Symbol | DC Characteristics | Test Conditions | Device | Min. | Typ. | Max. | Unit |
|-----------------|--|---|--|------|------|---------------|---------------|
| I_{FT} | LED Trigger Current (Rated I_{FT}) | Main Terminal Voltage = $3\text{ V}^{(3)}$ | MOC3061M MOC3062M MOC3162M MOC3063M MOC3163M | | | 15 10 5 | mA |
| V_{TM} | Peak On-State Voltage, Either Direction | $I_{\text{TM}} = 100\text{ mA}$ peak, $I_F = \text{rated } I_{\text{FT}}$ | All | | 1.8 | 3.0 | V |
| I_{H} | Holding Current, Either Direction | | All | | 500 | | μA |

Zero Crossing Characteristics

| Symbol | Characteristics | Test Conditions | Device | Min. | Typ. | Max. | Unit |
|-------------------|---|---|--|------|----------|----------|------|
| V_{INH} | Inhibit Voltage (MT1-MT2 voltage above which device will not trigger) | $I_F = \text{rated } I_{\text{FT}}$ | MOC3061M MOC3062M MOC3063M MOC3162M MOC3163M | | 12 12 | 20 15 | V |
| I_{DRM2} | Leakage in Inhibited State | $I_F = \text{rated } I_{\text{FT}}$, $\text{DRM} = 600\text{ V}$, off-state | All | | | 2 | mA |

Isolation Characteristics

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|------------------|----------------------------------|---|------|-----------|------|--------------------|
| V_{ISO} | Isolation Voltage ⁽⁴⁾ | $f = 60\text{ Hz}$, $t = 1\text{ Minute}$ | 4170 | | | V_{ACRMS} |
| R_{ISO} | Isolation Resistance | $V_{\text{I-O}} = 500\text{ V}_{\text{DC}}$ | | 10^{11} | | Ω |
| C_{ISO} | Isolation Capacitance | $V = 0\text{ V}$, $f = 1\text{ MHz}$ | | 0.2 | | pF |

Notes:

- Test voltage must be applied within dv/dt rating.
- This is static dv/dt. See Figure 11 for test circuit. Commutating dv/dt is a function of the load-driving thyristor(s) only.
- All devices are guaranteed to trigger at an I_F value less than or equal to max I_{FT} . Therefore, recommended operating I_F lies between max I_{FT} (15 mA for MOC3061M, 10 mA for MOC3062M and MOC3162M, 5 mA for MOC3063M and MOC3163M) and absolute maximum I_F (60 mA).
- Isolation voltage, V_{ISO} , is an internal device dielectric breakdown rating. For this test, pins 1 and 2 are common, and pins 4, 5 and 6 are common.

Typical Performance Curves



Figure 3. LED Forward Voltage vs. Forward Current

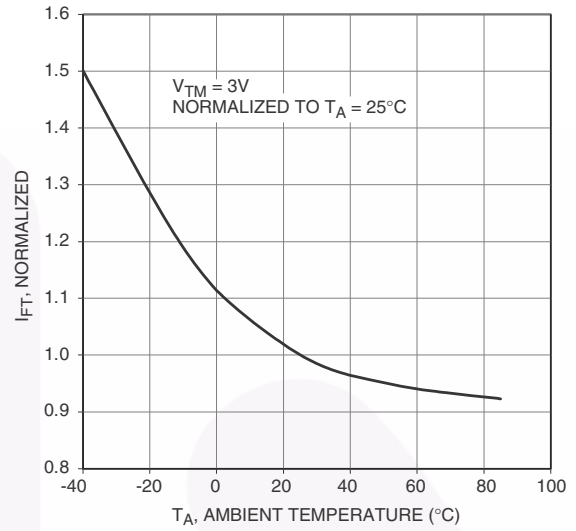


Figure 4. Trigger Current vs. Temperature



Figure 5. LED Current Required to Trigger vs. LED Pulse Width



Figure 6. Leakage Current, IDRM vs. Temperature

Typical Performance Curves (Continued)



Figure 7. I_{DRM2} , Leakage in Inhibit State vs. Temperature



Figure 8. On-State Characteristics



Figure 9. I_H , Holding Current vs. Temperature



Figure 10. Inhibit Voltage vs. Temperature

1. 100x scope probes are used, to allow high speeds and voltages.
2. The worst-case condition for static dv/dt is established by triggering the D.U.T. with a normal LED input current, then removing the current. The variable vernier resistor combined with various capacitor combinations allows the dv/dt to be gradually increased until the D.U.T. continues to trigger in response to the applied voltage pulse, even after the LED current has been removed. The dv/dt is then decreased until the D.U.T. stops triggering. t_{RC} is measured at this point and recorded.

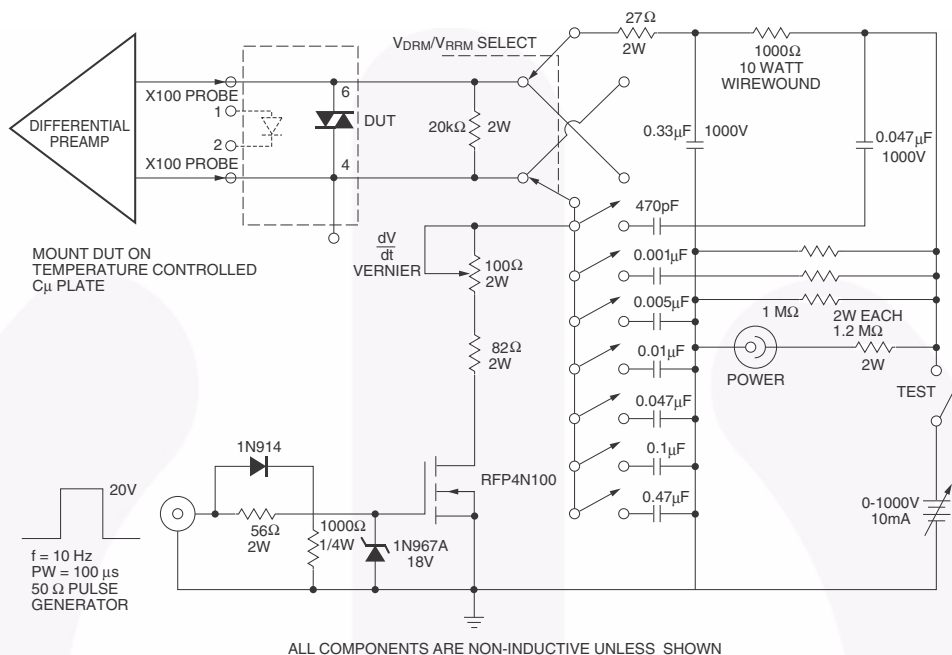


Figure 11. Circuit for Static $\frac{dv}{dt}$ Measurement of Power Thyristors

Basic Applications

Typical circuit for use when hot line switching is required. In this circuit the "hot" side of the line is switched and the load connected to the cold or neutral side. The load may be connected to either the neutral or hot line.

R_{in} is calculated so that I_F is equal to the rated I_{FT} of the part, 15mA for the MOC3061M, 10mA for the MOC3062M, or 5mA for the MOC3063M. The 39Ω resistor and 0.01μF capacitor are for snubbing of the triac and is often, but not always, necessary depending upon the particular triac and load used.

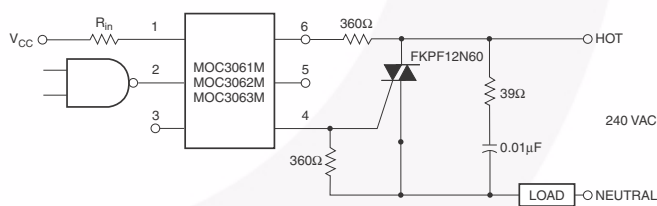


Figure 12. Hot-Line Switching Application Circuit

Suggested method of firing two, back-to-back SCR's with a Fairchild triac driver. Diodes can be 1N4001; resistors, R1 and R2, are optional 330Ω.

Note:

This optoisolator should not be used to drive a load directly. It is intended to be a trigger device only.

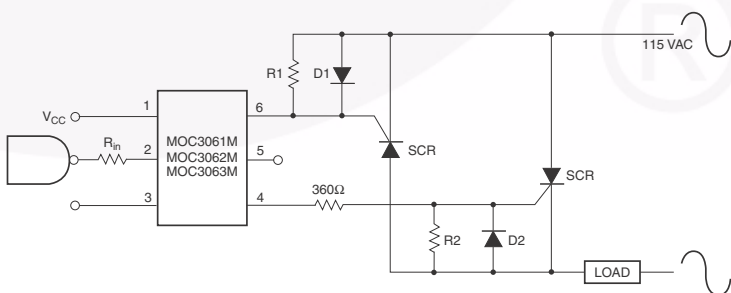


Figure 13. Inverse-Parallel SCR Driver Circuit

Reflow Profile



| Profile Feature | Pb-Free Assembly Profile |
|---|---------------------------|
| Temperature Minimum (T _{smin}) | 150°C |
| Temperature Maximum (T _{smax}) | 200°C |
| Time (t _s) from (T _{smin} to T _{smax}) | 60 seconds to 120 seconds |
| Ramp-up Rate (T _L to T _P) | 3°C/second maximum |
| Liquidous Temperature (T _L) | 217°C |
| Time (t _L) Maintained Above (T _L) | 60 seconds to 150 seconds |
| Peak Body Package Temperature | 260°C +0°C / -5°C |
| Time (t _p) within 5°C of 260°C | 30 seconds |
| Ramp-down Rate (T _P to T _L) | 6°C/second maximum |
| Time 25°C to Peak Temperature | 8 minutes maximum |

Figure 14. Reflow Profile

Ordering Information⁽⁵⁾

| Part Number | Package | Packing Method |
|--------------|--|----------------------------|
| MOC3061M | DIP 6-Pin | Tube (50 Units) |
| MOC3061SM | SMT 6-Pin (Lead Bend) | Tube (50 Units) |
| MOC3061SR2M | SMT 6-Pin (Lead Bend) | Tape and Reel (1000 Units) |
| MOC3061VM | DIP 6-Pin, DIN EN/IEC60747-5-5 Option | Tube (50 Units) |
| MOC3061SVM | SMT 6-Pin (Lead Bend), DIN EN/IEC60747-5-5 Option | Tube (50 Units) |
| MOC3061SR2VM | SMT 6-Pin (Lead Bend), DIN EN/IEC60747-5-5 Option | Tape and Reel (1000 Units) |
| MOC3061TVM | DIP 6-Pin, 0.4" Lead Spacing, DIN EN/IEC60747-5-5 Option | Tube (50 Units) |

Note:

5. The product orderable part number system listed in this table also applies to the MOC3062M, MOC3063M, MOC3162M, and MOC3163M product families.

Marking Information



Figure 15. Top Mark

| Top Mark Definitions | |
|----------------------|---|
| 1 | Fairchild Logo |
| 2 | Device Number |
| 3 | DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option) |
| 4 | One-Digit Year Code, e.g., '5' |
| 5 | Two-Digit Work Week, Ranging from '01' to '53' |
| 6 | Assembly Package Code |



- NOTES:
- A) NO STANDARD APPLIES TO THIS PACKAGE.
 - B) ALL DIMENSIONS ARE IN MILLIMETERS.
 - C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION
 - D) DRAWING FILENAME AND REVISION: MKT-N06BREV4.





LAND PATTERN RECOMMENDATION



NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION
- D) DRAWING FILENAME AND REVISION : MKT-N06CREV4.





NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION
- D) DRAWING FILENAME AND REVISION: MKT-N06Drev4



ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com
Order Literature: <http://www.onsemi.com/orderlit>
For additional information, please contact your local
Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[ON Semiconductor:](#)

[MOC3063SR2M](#) [MOC3063M](#) [MOC3063SR2VM](#) [MOC3063VM](#) [MOC3063SM](#) [MOC3063TVM](#) [MOC3063SVM](#)

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9